

50 MHz to 2 GHz Quadrature Demodulator ADL5387

FEATURES

Operating RF frequency 50 MHz to 2 GHz LO input at 2 × fLO 100 MHz to 4 GHz Input IP3: 31 dBm @ 900 MHz Input IP2: 62 dBm @ 900 MHz Input P1dB: 13 dBm @ 900 MHz Noise figure (NF) 12.0 dB @ 140 MHz 14.7 dB @ 900 MHz Voltage conversion gain > 4 dB Quadrature demodulation accuracy Phase accuracy ~0.4° Amplitude balance ~0.05 dB **Demodulation bandwidth ~240 MHz** Baseband I/Q drive 2 V p-p into 200 Ω Single 5 V supply

APPLICATIONS

QAM/QPSK RF/IF demodulators W-CDMA/CDMA/CDMA2000/GSM Microwave point-to-(multi)point radios Broadband wireless and WiMAX Broadband CATVs

GENERAL DESCRIPTION

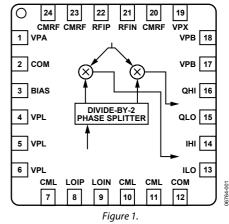
The ADL5387 is a broadband quadrature I/Q demodulator that covers an RF/IF input frequency range from 50 MHz to 2 GHz. With a NF = 13.2 dB, IP1dB = 12.7 dBm, and IIP3 = 32 dBm @ 450 MHz, the ADL5387 demodulator offers outstanding dynamic range suitable for the demanding infrastructure direct-conversion requirements. The differential RF/IF inputs provide a well-behaved broadband input impedance of 50 Ω and are best driven from a 1:1 balun for optimum performance.

Ultrabroadband operation is achieved with a divide-by-2 method for local oscillator (LO) quadrature generation. Over a wide range of LO levels, excellent demodulation accuracy is achieved with amplitude and phase balances ~0.05 dB and ~0.4°, respectively. The demodulated in-phase (I) and quadrature (Q) differential outputs are fully buffered and provide a voltage conversion gain of >4 dB. The buffered baseband outputs are capable of driving a 2 V p-p differential signal into 200 Ω .

Rev. 0

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FUNCTIONAL BLOCK DIAGRAM



The fully balanced design minimizes effects from second-order distortion. The leakage from the LO port to the RF port is <-70 dBc. Differential dc-offsets at the I and Q outputs are <10 mV. Both of these factors contribute to the excellent IIP2 specifications > 60 dBm.

The ADL5387 operates off a single 4.75 V to 5.25 V supply. The supply current is adjustable with an external resistor from the BIAS pin to ground.

The ADL5387 is fabricated using the Analog Devices, Inc. advanced silicon-germanium bipolar process and is available in a 24-lead exposed paddle LFCSP.

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REVISION HISTORY

10/07—Revision 0: Initial Version

SPECIFICATIONS

 $V_S = 5 V$, $T_A = 25^{\circ}$ C, $f_{RF} = 900 MHz$, $f_{IF} = 4.5 MHz$, $P_{LO} = 0 dBm$, BIAS pin open, $Z_O = 50 \Omega$, unless otherwise noted, baseband outputs differentially loaded with 450 Ω .

Parameter	Condition	Min	Тур	Max	Unit
OPERATING CONDITIONS					
LO Frequency Range	External input = 2xLO frequency	0.1		4	GHz
RF Frequency Range		0.05		2	GHz
LO INPUT	LOIP, LOIN				
Input Return Loss	AC-coupled into LOIP with LOIN bypassed, measured at 2 GHz		-10		dB
LO Input Level		-6	0	+6	dBm
I/Q BASEBAND OUTPUTS	QHI, QLO, IHI, ILO				
Voltage Conversion Gain	450 Ω differential load on I and Q outputs (@ 900 MHz)		4.3		dB
	200 Ω differential load on I and Q outputs (@ 900 MHz)		3.2		dB
Demodulation Bandwidth	1 V p-p signal 3 dB bandwidth		240		MHz
Quadrature Phase Error	@ 900 MHz		0.4		Degrees
I/Q Amplitude Imbalance			0.1		dB
Output DC Offset (Differential)	0 dBm LO input		±5		mV
Output Common-Mode			VPOS – 2.8		V
0.1 dB Gain Flatness			40		MHz
Output Swing	Differential 200 Ω load		2		V р-р
Peak Output Current	Each pin		12		mA
POWER SUPPLIES	VPA, VPL, VPB, VPX				
Voltage		4.75		5.25	V
Current	BIAS pin open		180		mA
	$RBIAS = 4 k\Omega$		157		mA
DYNAMIC PERFORMANCE @ RF = 140 MHz	RFIP, RFIN				
Conversion Gain			4.7		dB
Input P1dB (IP1dB)			13		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone		67		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone		31		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port		-100		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω		-95		dBc
I/Q Magnitude Imbalance			0.05		dB
I/Q Phase Imbalance			0.2		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port		-39		dBm
Noise Figure			12.0		dB
Noise Figure under Blocking Conditions	With a –5 dBm interferer 5 MHz away	1	14.4		dB

Parameter	Condition	Min Typ	Мах	Unit
DYNAMIC PERFORMANCE @ RF = 450 MHz				
Conversion Gain		4.4		dB
Input P1dB (IP1dB)		12.7		dBm
Second-Order Input Intercept (IIP2)	-5 dBm each input tone	69.2		dBm
Third-Order Input Intercept (IIP3)	-5 dBm each input tone	32.8		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port	-87		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω	-90		dBc
I/Q Magnitude Imbalance		0.05		dB
I/Q Phase Imbalance		0.6		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port	-38		dBm
Noise Figure		13.2		dB
DYNAMIC PERFORMANCE @ RF = 900 MHz				
Conversion Gain		4.3		dB
Input P1dB (IP1dB)		12.8		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone	61.7		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone	31.2		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port	-79		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω	-88		dBc
I/Q Magnitude Imbalance		0.05		dB
I/Q Phase Imbalance		0.2		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1XLO appearing at the BB port	-41		dBm
Noise Figure		14.7		dB
Noise Figure under Blocking Conditions	With a –5 dBm interferer 5 MHz away	15.8		dB
DYNAMIC PERFORMANCE @ RF = 1900 MHz				ub
Conversion Gain		3.8		dB
Input P1dB (IP1dB)		12.8		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone	59.8		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone	27.4		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port	-75		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω	-70		dBc
I/Q Magnitude Imbalance		0.05		dB
I/Q Phase Imbalance		0.3		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port	-43		dBm
Noise Figure		16.5		dB
Noise Figure under Blocking Conditions	With a –5 dBm interferer 5 MHz away	18.7		dB

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage VPOS1, VPOS2, VPOS3	5.5 V
LO Input Power	13 dBm (re: 50 Ω)
RF/IF Input Power	15 dBm (re: 50 Ω)
Internal Maximum Power Dissipation	1100 mW
θ _{JA}	54°C/W
Maximum Junction Temperature	150°C
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	–65°C to +125°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

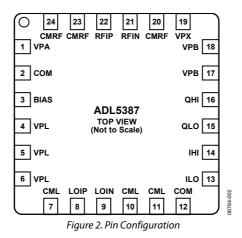


Table 3. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 4 to 6, 17 to 19	VPA, VPL, VPB, VPX	Supply. Positive supply for LO, IF, biasing and baseband sections, respectively. These pins should be decoupled to board ground using appropriate sized capacitors.
2, 7, 10 to 12, 20, 23, 24	COM, CML, CMRF	Ground. Connect to a low impedance ground plane.
3	BIAS	Bias Control. A resistor can be connected between BIAS and COM to reduce the mixer core current. The default setting for this pin is open.
8, 9	LOIP, LOIN	Local Oscillator. External LO input is at 2xLO frequency. A single-ended LO at 0 dBm can be applied through a 1000 pF capacitor to LOIP. LOIN should be ac-grounded, also using a 1000 pF. These inputs can also be driven differentially through a balun (recommended balun is M/A-COM ETC1-1-13).
13 to 16	ILO, IHI, QLO, QHI	I-Channel and Q-Channel Mixer Baseband Outputs. These outputs have a 50 Ω differential output impedance (25 Ω per pin). The bias level on these pins is equal to VPOS – 2.8 V. Each output pair can swing 2 V p-p (differential) into a load of 200 Ω . Output 3 dB bandwidth is 240 MHz.
21, 22	RFIN, RFIP	RF Input. A single-ended 50 Ω signal can be applied to the RF inputs through a 1:1 balun (recommended balun is M/A-COM ETC1-1-13). Ground-referenced inductors must also be connected to RFIP and RFIN (recommended values = 120 nH).
	EP	Exposed Paddle. Connect to a low impedance ground plane

TYPICAL PERFORMANCE CHARACTERISTICS

 $V_S = 5 V$, $T_A = 25^{\circ}$ C, LO drive level = 0 dBm, $R_{BIAS} =$ open, unless otherwise noted.

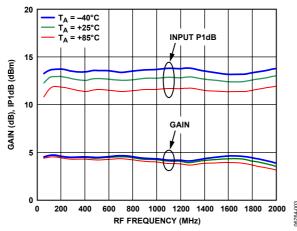


Figure 3. Conversion Gain and Input 1 dB Compression Point (IP1dB) vs. RF Frequency

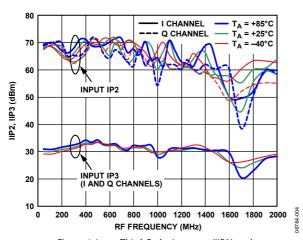


Figure 4. Input Third-Order Intercept (IIP3) and Input Second-Order Intercept Point (IIP2) vs. RF Frequency

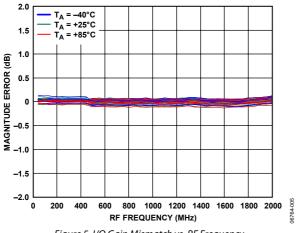
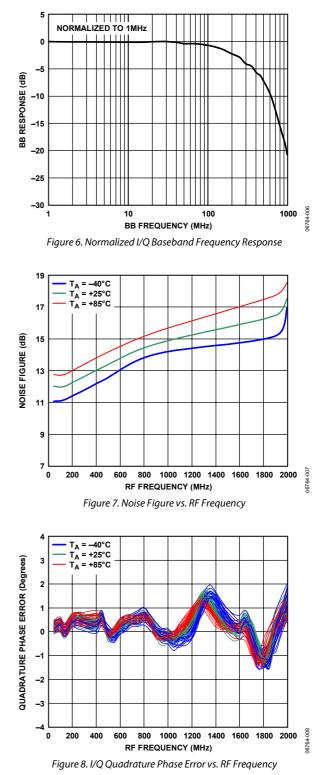
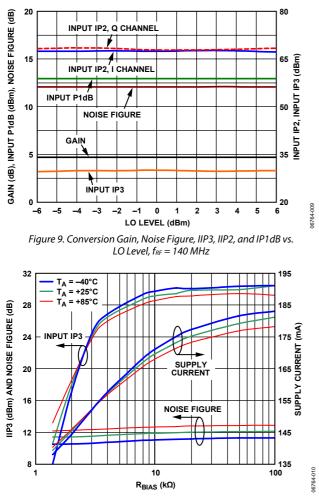
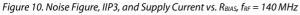


Figure 5. I/Q Gain Mismatch vs. RF Frequency







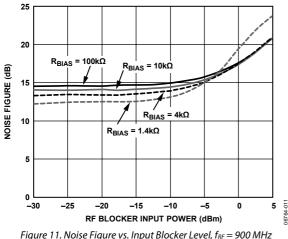


Figure 11. Noise Figure vs. Input Blocker Level, f_{RF} = 900 MHz (RF Blocker 5 MHz Offset)

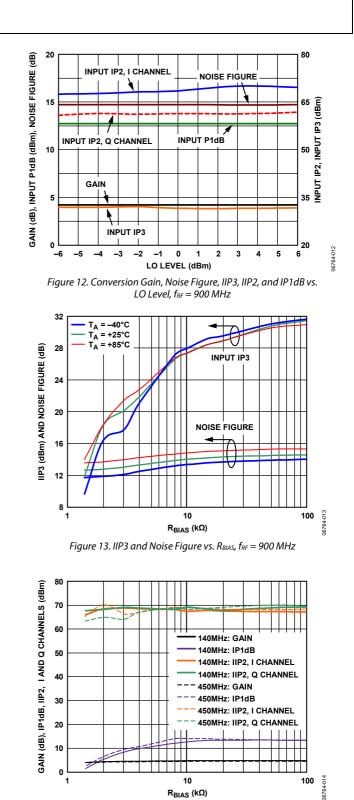


Figure 14. Conversion Gain, IP1dB, IIP2 I Channel, and IIP2 Q Channel vs. RBIAS

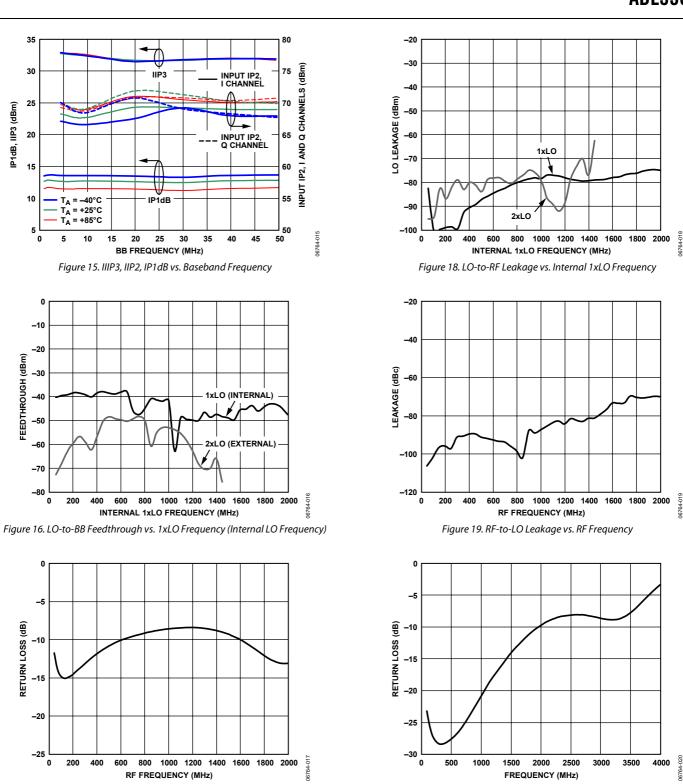
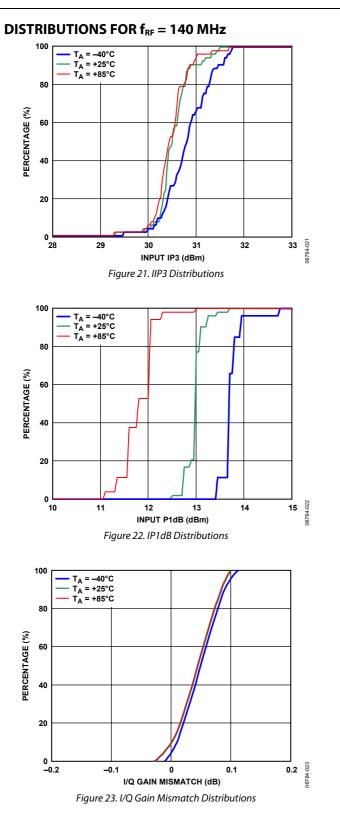
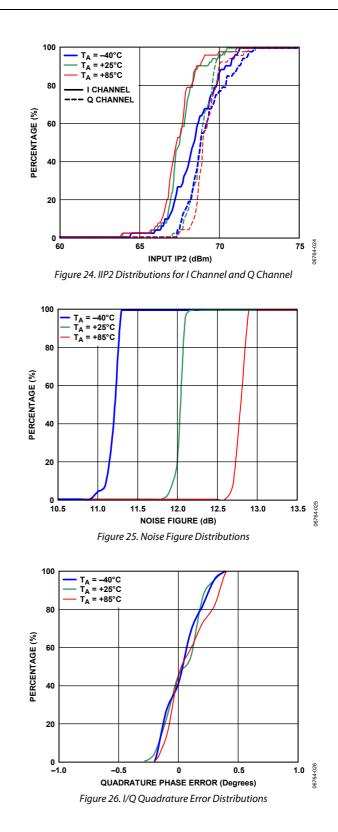
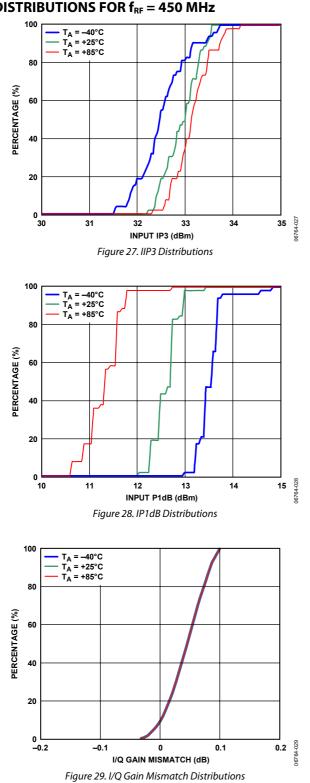


Figure 17. RF Port Return Loss vs. RF Frequency, Measured on Characterization Board through ETC1-1-13 Balun with 120 nH Bias Inductors

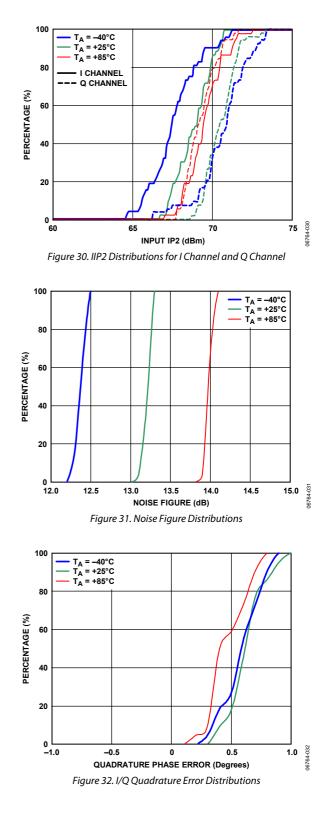
Figure 20. Single-Ended LO Port Return Loss vs. LO Frequency, LOIN AC-Coupled to Ground

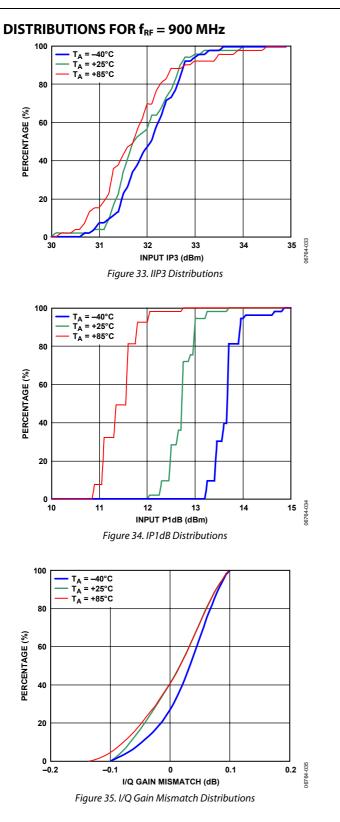


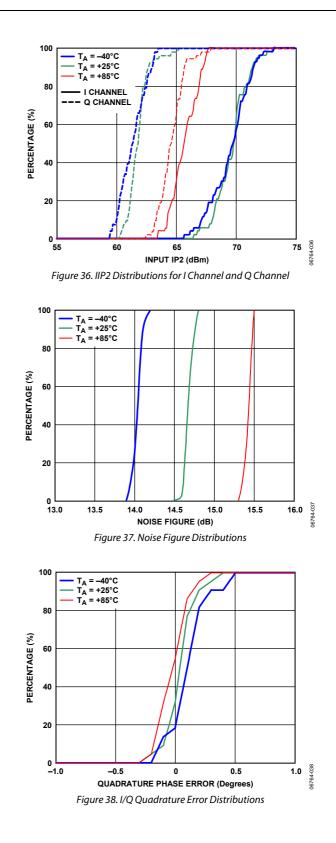


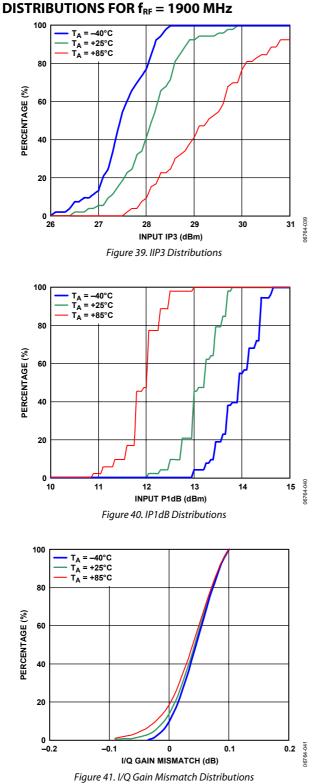


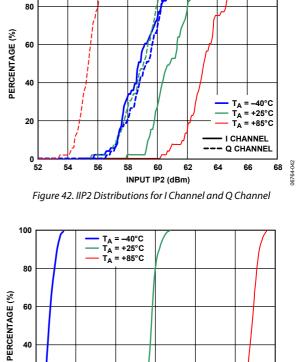




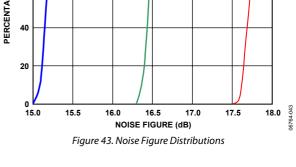


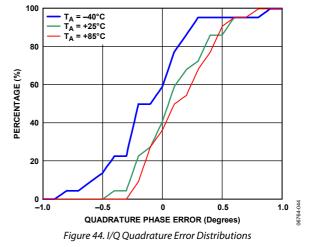






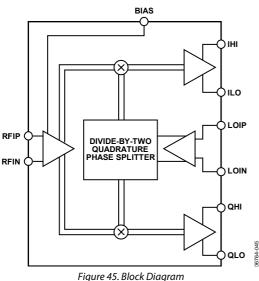
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CIRCUIT DESCRIPTION

The ADL5387 can be divided into five sections: the local oscillator (LO) interface, the RF voltage-to-current (V-to-I) converter, the mixers, the differential emitter follower outputs, and the bias circuit. A detailed block diagram of the device is shown in Figure 45.



The LO interface generates two LO signals at 90° of phase difference to drive two mixers in quadrature. RF signals are converted into currents by the V-to-I converters that feed into the two mixers. The differential I and Q outputs of the mixers are buffered via emitter followers. Reference currents to each section are generated by the bias circuit. A detailed description of each section follows.

LO INTERFACE

The LO interface consists of a buffer amplifier followed by a frequency divider that generate two carriers at half the input frequency and in quadrature with each other. Each carrier is then amplified and amplitude-limited to drive the double-balanced mixers.

V-TO-I CONVERTER

The differential RF input signal is applied to a resistively degenerated common base stage, which converts the differential input voltage to output currents. The output currents then modulate the two half-frequency LO carriers in the mixer stage.

MIXERS

The ADL5387 has two double-balanced mixers: one for the in-phase channel (I channel) and one for the quadrature channel (Q channel). These mixers are based on the Gilbert cell design of four cross-connected transistors. The output currents from the two mixers are summed together in the resistive loads that then feed into the subsequent emitter follower buffers.

EMITTER FOLLOWER BUFFERS

The output emitter followers drive the differential I and Q signals off-chip. The output impedance is set by on-chip 25 Ω series resistors that yield a 50 Ω differential output impedance for each baseband port. The fixed output impedance forms a voltage divider with the load impedance that reduces the effective gain. For example, a 500 Ω differential load has 1 dB lower effective gain than a high (10 k Ω) differential load impedance.

BIAS CIRCUIT

A band gap reference circuit generates the proportional-toabsolute temperature (PTAT) as well as temperature-independent reference currents used by different sections. The mixer current can be reduced via an external resistor between the BIAS pin and ground. When the BIAS pin is open, the mixer runs at maximum current and hence the greatest dynamic range. The mixer current can be reduced by placing a resistance to ground; therefore, reducing overall power consumption, noise figure, and IIP3. The effect on each of these parameters is shown in Figure 10, Figure 13, and Figure 14.

APPLICATIONS INFORMATION BASIC CONNECTIONS

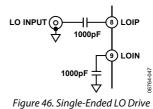
Figure 47 shows the basic connections schematic for the ADL5387.

POWER SUPPLY

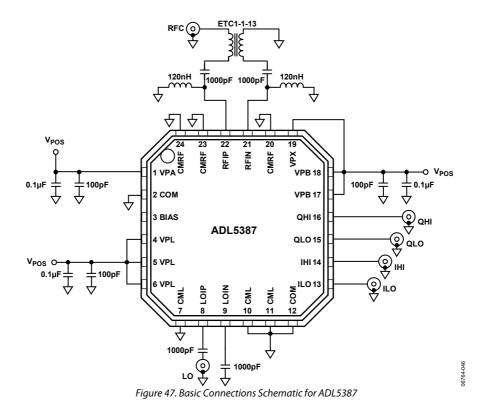
The nominal voltage supply for the ADL5387 is 5 V and is applied to the VPA, VPB, VPL, and VPX pins. Ground should be connected to the COM, CML, and CMRF pins. Each of the supply pins should be decoupled using two capacitors; recommended capacitor values are 100 pF and 0.1 μ F.

LOCAL OSCILLATOR (LO) INPUT

The LO port is driven in a single-ended manner. The LO signal must be ac-coupled via a 1000 pF capacitor directly into LOIP, and LOIN is ac-coupled to ground also using a 1000 pF capacitor. The LO port is designed for a broadband 50 Ω match and therefore exhibits excellent return loss from 100 MHz to 4 GHz. The LO return loss can be seen in Figure 20. Figure 46 shows the LO input configuration.

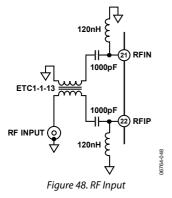


The recommended LO drive level is between -6 dBm and +6 dBm. The LO frequency at the input to the device should be twice that of the desired LO frequency at the mixer core. The applied LO frequency range is between 100 MHz and 4 GHz.

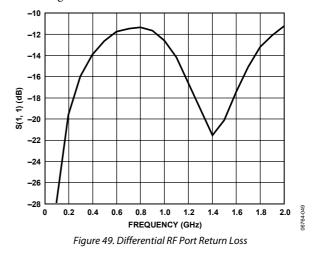


RF INPUT

The RF inputs have a differential input impedance of approximately 50 Ω . For optimum performance, the RF port should be driven differentially through a balun. The recommended balun is M/A-COM ETC1-1-13. The RF inputs to the device should be ac-coupled with 1000 pF capacitors. Ground-referenced choke inductors must also be connected to RFIP and RFIN (recommended value = 120 nH, Coilcraft 0402CS-R12XJL) for appropriate biasing. Several important aspects must be taken into account when selecting an appropriate choke inductor for this application. First, the inductor must be able to handle the approximately 40 mA of standing dc current being delivered from each of the RF input pins (RFIP, RFIN). (The suggested 0402 inductor has a 50 mA current rating). The purpose of the choke inductors is to provide a very low resistance dc path to ground and high ac impedance at the RF frequency so as not to affect the RF input impedance. A choke inductor that has a selfresonant frequency greater than the RF input frequency ensures that the choke is still looking inductive and therefore has a more predictable ac impedance (jwL) at the RF frequency. Figure 48 shows the RF input configuration.



The differential RF port return loss has been characterized as shown in Figure 49.



BASEBAND OUTPUTS

The baseband outputs QHI, QLO, IHI, and ILO are fixed impedance ports. Each baseband pair has a 50 Ω differential output impedance. The outputs can be presented with differential loads as low as 200 Ω (with some degradation in linearity and gain) or high impedance differential loads (500 Ω or greater impedance yields the same excellent linearity) that is typical of an ADC. The TCM9-1 9:1 balun converts the differential IF output to single-ended. When loaded with 50 Ω , this balun presents a 450 Ω load to the device. The typical maximum linear voltage swing for these outputs is 2 V p-p differential. The bias level on these pins is equal to VPOS – 2.8 V. The output 3 dB bandwidth is 240 MHz. Figure 50 shows the baseband output configuration.

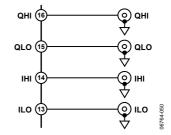


Figure 50. Baseband Output Configuration

ERROR VECTOR MAGNITUDE (EVM) PERFORMANCE

EVM is a measure used to quantify the performance of a digital radio transmitter or receiver. A signal received by a receiver would have all constellation points at the ideal locations; however, various imperfections in the implementation (such as carrier leakage, phase noise, and quadrature error) cause the actual constellation points to deviate from the ideal locations.

The ADL5387 shows excellent EVM performance for various modulation schemes. Figure 51 shows typical EVM performance over input power range for a point-to-point application with 16 QAM modulation schemes and zero-IF baseband. The differential dc offsets on the ADL5387 are in the order of a few mV. However, ac coupling the baseband outputs with 10 μ F capacitors helps to eliminate dc offsets and enhances EVM performance. With a 10 MHz BW signal, 10 μ F ac coupling capacitors with the 500 Ω differential load results in a high-pass corner frequency of ~64 Hz which absorbs an insignificant amount of modulated signal energy from the baseband signal. By using ac coupling capacitors at the baseband outputs, the dc offset effects, which can limit dynamic range at low input power levels, can be eliminated.

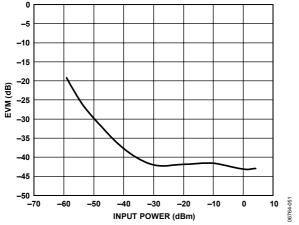


Figure 51. RF = 140 MHz, IF = 0 Hz, EVM vs. Input Power for a 16 QAM 10 Msym/s Signal (AC-Coupled Baseband Outputs)

Figure 52 shows the EVM performance of the ADL5387 when ac-coupled, with an IEEE 802.16e WiMAX signal.

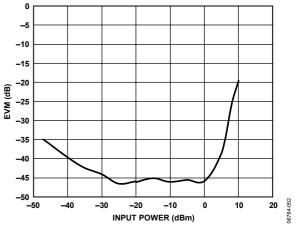


Figure 52. RF = 750MHz MHz, IF = 0 Hz, EVM vs. Input Power for a 16 QAM 10 MHz Bandwidth Mobile WiMAX Signal (AC-Coupled Baseband Outputs)

Figure 53 exhibits the zero IF EVM performance of a WCDMA

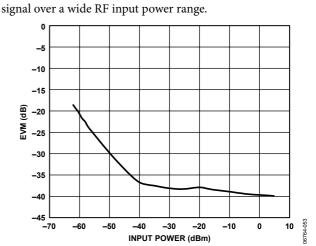


Figure 53. RF = 1950 MHz, IF = 0 Hz, EVM vs. Input Power for a WCDMA (AC-Coupled Baseband Outputs)

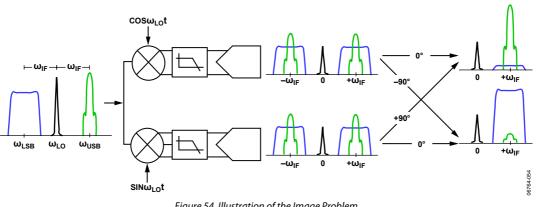
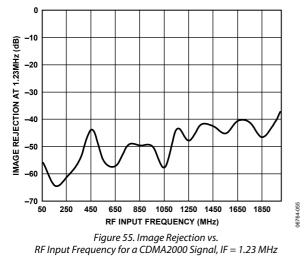


Figure 54. Illustration of the Image Problem

LOW IF IMAGE REJECTION

The image rejection ratio is the ratio of the intermediate frequency (IF) signal level produced by the desired input frequency to that produced by the image frequency. The image rejection ratio is expressed in decibels. Appropriate image rejection is critical because the image power can be much higher than that of the desired signal, thereby plaguing the down conversion process. Figure 54 illustrates the image problem. If the upper sideband (lower sideband) is the desired band, a 90° shift to the Q channel (I channel) cancels the image at the lower sideband (upper sideband).

Figure 55 shows the excellent image rejection capabilities of the ADL5387 for low IF applications, such as CDMA2000. The ADL5387 exhibits image rejection greater than 45 dB over the broad frequency range for an IF = 1.23 MHz.



EXAMPLE BASEBAND INTERFACE

In most direct conversion receiver designs, it is desirable to select a wanted carrier within a specified band. The desired channel can be demodulated by tuning the LO to the appropriate carrier frequency. If the desired RF band contains multiple carriers of interest, the adjacent carriers would also be down converted to a lower IF frequency. These adjacent carriers can be problematic if they are large relative to the wanted carrier as they can overdrive the baseband signal detection circuitry. As a result, it is often necessary to insert a filter to provide sufficient rejection of the adjacent carriers.

It is necessary to consider the overall source and load impedance presented by the ADL5387 and ADC input to design the filter network. The differential baseband output impedance of the ADL5387 is 50 Ω . The ADL5387 is designed to drive a high impedance ADC input. It may be desirable to terminate the ADC input down to lower impedance by using a terminating resistor, such as 500 Ω . The terminating resistor helps to better define the input impedance at the ADC input. The order and type of filter network depends on the desired high frequency rejection required, pass-band ripple, and group delay. Filter design tables provide outlines for various filter types and orders, illustrating the normalized inductor and capacitor values for a 1 Hz cutoff frequency and 1 Ω load. After scaling the normalized prototype element values by the actual desired cut-off frequency and load impedance, the series reactance elements are halved to realize the final balanced filter network component values.

As an example, a second-order, Butterworth, low-pass filter design is shown in Figure 56 where the differential load impedance is 500 Ω , and the source impedance of the ADL5387 is 50 Ω . The normalized series inductor value for the 10-to-1, load-to-source impedance ratio is 0.074 H, and the normalized shunt capacitor is 14.814 F. For a 10.9 MHz cutoff frequency, the single-ended equivalent circuit consists of a 0.54 μ H series inductor followed by a 433 pF shunt capacitor.

The balanced configuration is realized as the 0.54 μ H inductor is split in half to realize the network shown in Figure 56.

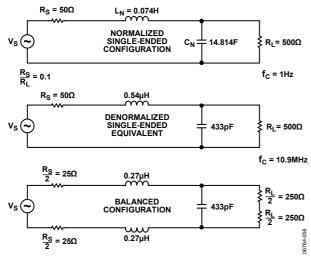


Figure 56. Second-Order, Butterworth, Low-Pass Filter Design Example

A complete design example is shown in Figure 59. A sixth-order Butterworth differential filter having a 1.9 MHz corner frequency interfaces the output of the ADL5387 to that of an ADC input. The 500 Ω load resistor defines the input impedance of the ADC. The filter adheres to typical direct conversion WCDMA applications, where 1.92 MHz away from the carrier IF frequency, 1 dB of rejection is desired and 2.7 MHz away 10 dB of rejection is desired.

10 E MAGNITUDE RESPONSE (dB) -5 -10 -15 -20 06764-157 0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 FREQUENCY (MHz) Figure 57. Baseband Filter Response 900 800 700 600 DELAY (ns) 500 400 300 200 100 06764-158 0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 FREQUENCY (MHz) Figure 58. Baseband Filter Group Delay

Figure 57 and Figure 58 show the measured frequency response and group delay of the filter.

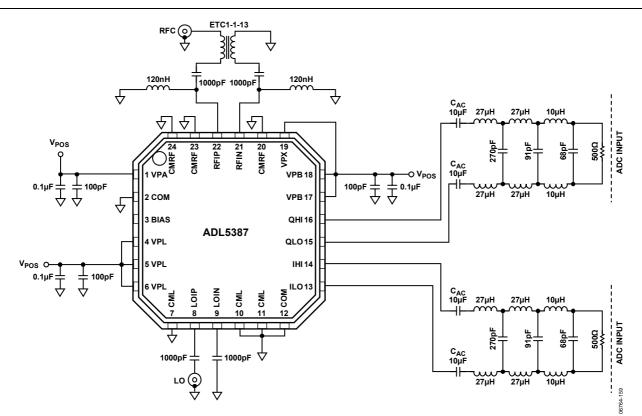
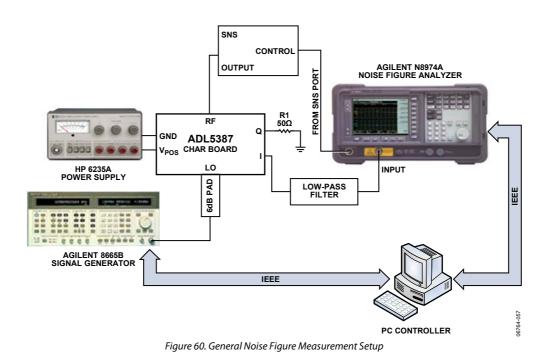


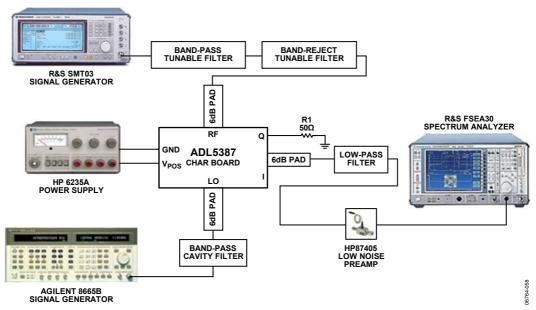
Figure 59. Sixth Order Low-Pass Butterworth Baseband Filter Schematic

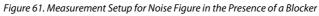
CHARACTERIZATION SETUPS

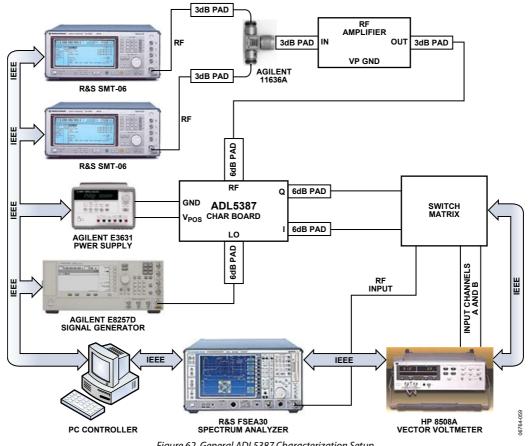
Figure 60 to Figure 62 show the general characterization bench setups used extensively for the ADL5387. The setup shown in Figure 62 was used to do the bulk of the testing and used sinusoidal signals on both the LO and RF inputs. An automated Agilent-VEE program was used to control the equipment over the IEEE bus. This setup was used to measure gain, IP1dB, IIP2, IIP3, I/Q gain match, and quadrature error. The ADL5387 characterization board had a 9-to-1 impedance transformer on each of the differential baseband ports to do the differential-to-singleended conversion.

The two setups shown in Figure 60 and Figure 61 were used for making NF measurements. Figure 60 shows the setup for measuring NF with no blocker signal applied while Figure 61 was used to measure NF in the presence of a blocker. For both setups, the noise was measured at a baseband frequency of 10 MHz. For the case where a blocker was applied, the output blocker was at 15 MHz baseband frequency. Note that great care must be taken when measuring NF in the presence of a blocker. The RF blocker generator must be filtered to prevent its noise (which increases with increasing generator output power) from swamping the noise contribution of the ADL5387. At least 30 dB of attention at the RF and image frequencies is desired. For example, with a 2xLO of 1848 MHz applied to the ADL5387, the internal 1xLO is 924 MHz. To obtain a 15 MHz output blocker signal, the RF blocker generator is set to 939 MHz and the filters tuned such that there is at least 30 dB of attenuation from the generator at both the desired RF frequency (934 MHz) and the image RF frequency (914 MHz). Finally, the blocker must be removed from the output (by the 10 MHz low-pass filter) to prevent the blocker from swamping the analyzer.









EVALUATION BOARD

The ADL5387 evaluation board is available. The board can be used for single-ended or differential baseband analysis. The default configuration of the board is for single-ended baseband analysis.

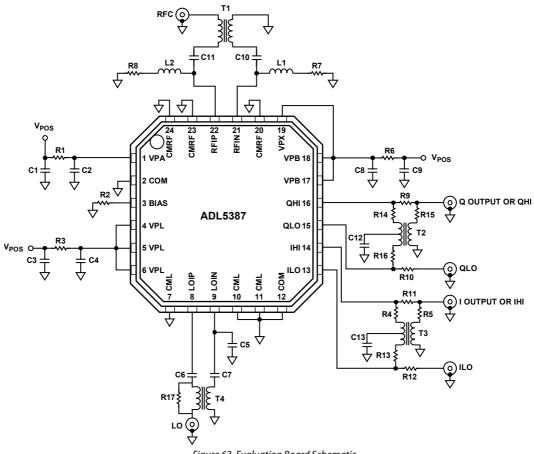


Figure 63. Evaluation Board Schematic

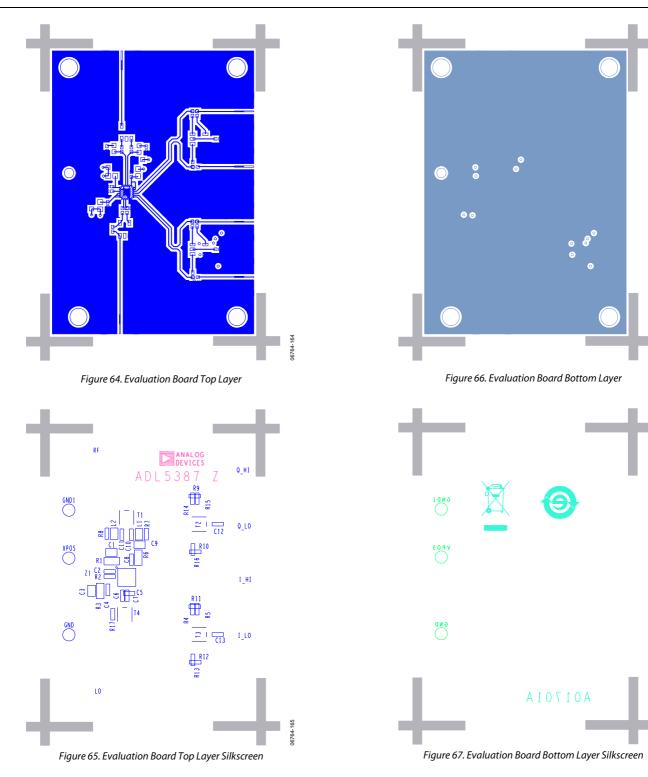
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Table 4. Evaluation Board Configuration Options

Component	Function	Default Condition
VPOS, GND	Power Supply and Ground Vector Pins.	Not Applicable
R1, R3, R6	Power Supply Decoupling. Shorts or power supply decoupling resistors.	R1, R3, R6 = 0 Ω (0805)
C1, C2, C3, C4, C8, C9	The capacitors provide the required dc coupling up to 2 GHz.	C2, C4, C8 = 100 pF (0402) C1, C3, C9 = 0.1 μF (0603)
C5, C6, C7, C10, C11	AC Coupling Capacitors. These capacitors provide the required ac coupling from 50 MHz to 2 GHz.	C5, C6, C10, C11 = 1000 pF (0402), C7 = Open
R4, R5, R9 to R16	Single-Ended Baseband Output Path. This is the default configuration of the evaluation board. R14 to R16 and R4, R5, and R13 are populated for appropriate balun interface. R9, R10 and R11, R12 are not populated. Baseband outputs are taken from QHI and IHI. The user can reconfigure the board to use full differential baseband outputs. R9 to R12 provide a means to bypass the 9:1 TCM9-1 transformer to allow for differential baseband outputs. Access the differential baseband signals by populating R9 to R12 with 0 Ω and not populating R4, R5, R13 to R16. This way the transformer does not need to be removed. The baseband outputs are taken from the SMAs of Q_HI, Q_LO, I_HI, and I_LO.	R4, R5, R13 to R16 = 0 Ω (0402), R9 to R12 = Open
L1, L2, R7, R8	Input Biasing. Inductance and resistance sets the input biasing of the common base input stage. Default value is 120 nH.	L1, L2 = 120 nH (0402) R7, R8 = 0 Ω (0402)
Т2, Т3	IF Output Interface. TCM9-1 converts a differential high impedance IF output to a single- ended output. When loaded with 50 Ω , this balun presents a 450 Ω load to the device. The center tap can be decoupled through a capacitor to ground.	T2, T3 = TCM9-1, 9:1 (Mini-Circuits)
C12, C13	Decoupling Capacitors. C12 and C13 are the decoupling capacitors used to reject noise on the center tap of the TCM9-1.	C12, C13 = 0.1 μF (0402)
R17	LO Input Interface. The LO is driven as a single-ended signal. Although, there is no performance change for a differential signal drive, the option is available by placing a transformer (T4, ETC1-1-13) on the LO input path.	R17 = 0 Ω (0402)
T1	RF Input Interface. ETC1-1-13 is a 1:1 RF balun that converts the single-ended RF input to differential signal.	T1 = ETC1-1-13, 1:1 (M/A COM)
R2	R _{BIAS} . Optional bias setting resistor. See the Bias Circuit section to see how to use this feature.	R2 = Open

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OUTLINE DIMENSIONS

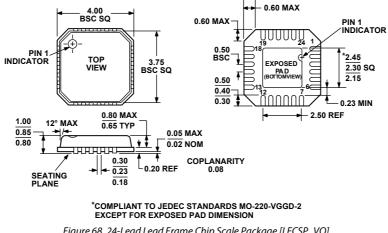


Figure 68. 24-Lead Lead Frame Chip Scale Package [LFCSP_VQ] 4 mm × 4 mm Body, Very Thin Quad (CP-24-2) Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Ordering Quantity
ADL5387ACPZ-R71	-40°C to +85°C	24-Lead LFCSP_VQ, 7"Tape and Reel	CP-24-2	1,500
ADL5387ACPZ-WP ¹	-40°C to +85°C	24-Lead LFCSP_VQ, Waffle Pack	CP-24-2	64
ADL5387-EVALZ ¹		Evaluation Board		

 1 Z = RoHS Compliant Part.

NOTES

NOTES

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